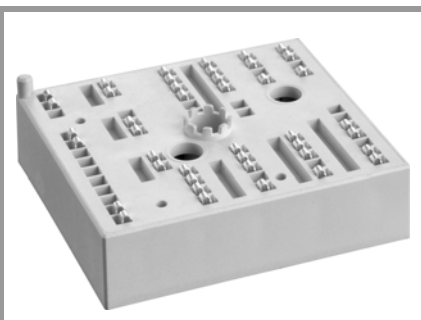


SKiiP 24ACC12T4V10



MiniSKiiP® 2

Twin 6-pack

SKiiP 24ACC12T4V10

Features

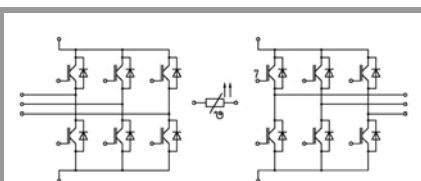
- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

Typical Applications*

- 4Q inverters

Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)
- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage $V_{DC} \leq 800\text{V}$
- Temperature sensor: no basic insulation to main circuit, signal processing with reference to -DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information

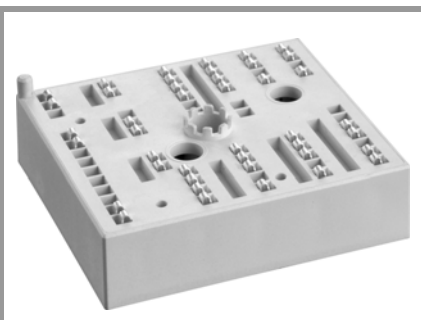


ACC

Absolute Maximum Ratings

| Symbol | Conditions | Values | Unit | |
|---------------------|--|---------------------------|------------------|---------------|
| IGBT 1 - 6 | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | 1200 | V | |
| I_C | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 41 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 34 | A |
| I_C | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 45 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 37 | A |
| I_{Cnom} | | 25 | A | |
| I_{CRM} | $I_{CRM} = 3 \times I_{Cnom}$ | 75 | A | |
| V_{GES} | | -20 ... 20 | V | |
| t_{psc} | $V_{CC} = 800\text{ V}$ | $T_j = 150^\circ\text{C}$ | 10 | μs |
| | $V_{GE} \leq 15\text{ V}$ | | | |
| | $V_{CES} \leq 1200\text{ V}$ | | | |
| T_j | | -40 ... 175 | $^\circ\text{C}$ | |
| IGBT 7 - 12 | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | 1200 | V | |
| I_C | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 52 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 43 | A |
| I_C | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 58 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 48 | A |
| I_{Cnom} | | 35 | A | |
| I_{CRM} | $I_{CRM} = 3 \times I_{Cnom}$ | 105 | A | |
| V_{GES} | | -20 ... 20 | V | |
| t_{psc} | $V_{CC} = 800\text{ V}$ | $T_j = 150^\circ\text{C}$ | 10 | μs |
| | $V_{GE} \leq 15\text{ V}$ | | | |
| | $V_{CES} \leq 1200\text{ V}$ | | | |
| T_j | | -40 ... 175 | $^\circ\text{C}$ | |
| Diode 1 - 6 | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | 1200 | V | |
| I_F | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 32 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 26 | A |
| I_F | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 35 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 28 | A |
| I_{Fnom} | | 25 | A | |
| I_{FRM} | $I_{FRM} = 3 \times I_{Fnom}$ | 75 | A | |
| I_{FSM} | 10 ms, sin 180°, $T_j = 150^\circ\text{C}$ | 100 | A | |
| T_j | | -40 ... 175 | $^\circ\text{C}$ | |
| Diode 7 - 12 | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | 1200 | V | |
| I_F | $\lambda_{paste}=0.8\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 44 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 35 | A |
| I_F | $\lambda_{paste}=2.5\text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 49 | A |
| | $T_j = 175^\circ\text{C}$ | $T_s = 70^\circ\text{C}$ | 40 | A |
| I_{Fnom} | | 35 | A | |
| I_{FRM} | $I_{FRM} = 3 \times I_{Fnom}$ | 105 | A | |
| I_{FSM} | 10 ms, sin 180°, $T_j = 150^\circ\text{C}$ | 170 | A | |
| T_j | | -40 ... 175 | $^\circ\text{C}$ | |
| Module | | | | |
| $I_{t(RMS)}$ | 20 A per spring | 40 | A | |
| T_{stg} | | -40 ... 125 | $^\circ\text{C}$ | |
| V_{isol} | AC sinus 50 Hz, 1 min | 2500 | V | |

SKiiP 24ACC12T4V10



MiniSKiiP® 2

Twin 6-pack

SKiiP 24ACC12T4V10

Features

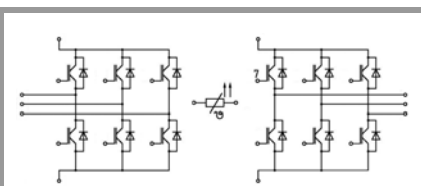
- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

Typical Applications*

- 4Q inverters

Remarks

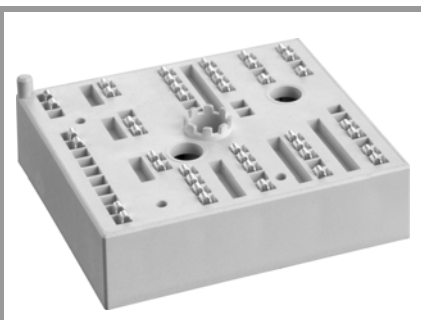
- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)
- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage $V_{DC} \leq 800\text{V}$
- Temperature sensor: no basic insulation to main circuit, signal processing with reference to -DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information



ACC

| Characteristics | | | | | | |
|--------------------|---|---------------------------|------|------|------|------------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| IGBT 1 - 6 | | | | | | |
| $V_{CE(sat)}$ | $I_C = 25\text{ A}$ $V_{GE} = 15\text{ V}$ chipllevel | $T_j = 25^\circ\text{C}$ | | 1.85 | 2.10 | V |
| | | $T_j = 150^\circ\text{C}$ | | 2.25 | 2.45 | V |
| V_{CE0} | chipllevel | $T_j = 25^\circ\text{C}$ | | 0.80 | 0.90 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.70 | 0.80 | V |
| r_{CE} | $V_{GE} = 15\text{ V}$ chipllevel | $T_j = 25^\circ\text{C}$ | | 42 | 48 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 62 | 66 | m Ω |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}\text{ V}, I_C = 1\text{ mA}$ | | 5 | 5.8 | 6.5 | V |
| I_{CES} | $V_{GE} = 0\text{ V}$ $V_{CE} = 1200\text{ V}$ | $T_j = 25^\circ\text{C}$ | | 0.1 | 0.3 | mA |
| | | | | | | mA |
| C_{ies} | $V_{CE} = 25\text{ V}$ | $f = 1\text{ MHz}$ | | 1.43 | | nF |
| C_{oes} | $V_{GE} = 0\text{ V}$ | $f = 1\text{ MHz}$ | | 0.12 | | nF |
| C_{res} | | $f = 1\text{ MHz}$ | | 0.09 | | nF |
| Q_G | $V_{GE} = -8\text{ V} \dots +15\text{ V}$ | | | 142 | | nC |
| R_{Gint} | $T_j = 25^\circ\text{C}$ | | | 0.0 | | Ω |
| $t_{d(on)}$ | $V_{CC} = 600\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 96 | | ns |
| t_r | $I_C = 25\text{ A}$ $R_{G\ on} = 39\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 80 | | ns |
| | | | | | | |
| E_{on} | $R_{G\ off} = 39\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 4.2 | | mJ |
| $t_{d(off)}$ | $di/dt_{on} = 250\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 400 | | ns |
| t_f | $di/dt_{off} = 400\text{ A}/\mu\text{s}$ $du/dt = 3600\text{ V}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 51 | | ns |
| | | | | | | |
| E_{off} | $V_{GE} = +15/-15\text{ V}$ $L_s = 22\text{ nH}$ | $T_j = 150^\circ\text{C}$ | | 2.6 | | mJ |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 1 | | K/W |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.84 | | K/W |
| IGBT 7 - 12 | | | | | | |
| $V_{CE(sat)}$ | $I_C = 35\text{ A}$ $V_{GE} = 15\text{ V}$ chipllevel | $T_j = 25^\circ\text{C}$ | | 1.85 | 2.10 | V |
| | | $T_j = 150^\circ\text{C}$ | | 2.25 | 2.45 | V |
| V_{CE0} | chipllevel | $T_j = 25^\circ\text{C}$ | | 0.80 | 0.90 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.70 | 0.80 | V |
| r_{CE} | $V_{GE} = 15\text{ V}$ chipllevel | $T_j = 25^\circ\text{C}$ | | 30 | 34 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 44 | 47 | m Ω |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}\text{ V}, I_C = 1\text{ mA}$ | | 5 | 5.8 | 6.5 | V |
| I_{CES} | $V_{GE} = 0\text{ V}$ $V_{CE} = 1200\text{ V}$ | $T_j = 25^\circ\text{C}$ | | 0.1 | 0.3 | mA |
| | | | | - | | mA |
| C_{ies} | $V_{CE} = 25\text{ V}$ | $f = 1\text{ MHz}$ | | 1.95 | | nF |
| C_{oes} | $V_{GE} = 0\text{ V}$ | $f = 1\text{ MHz}$ | | 0.16 | | nF |
| C_{res} | | $f = 1\text{ MHz}$ | | 0.12 | | nF |
| Q_G | $V_{GE} = -8\text{ V} \dots +15\text{ V}$ | | | 200 | | nC |
| R_{Gint} | $T_j = 25^\circ\text{C}$ | | | 0 | | Ω |
| $t_{d(on)}$ | $V_{CC} = 600\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 52 | | ns |
| t_r | $I_C = 35\text{ A}$ $R_{G\ on} = 16\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 34 | | ns |
| | | | | | | |
| E_{on} | $R_{G\ off} = 16\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 3.9 | | mJ |
| $t_{d(off)}$ | $di/dt_{on} = 680\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 337 | | ns |
| t_f | $di/dt_{off} = 560\text{ A}/\mu\text{s}$ $du/dt = 4000\text{ V}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 53 | | ns |
| | | | | | | |
| E_{off} | $V_{GE} = +15/-15\text{ V}$ $L_s = 22\text{ nH}$ | $T_j = 150^\circ\text{C}$ | | 3.5 | | mJ |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 0.85 | | K/W |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.7 | | K/W |

SKiiP 24ACC12T4V10



MiniSKiiP® 2

Twin 6-pack

SKiiP 24ACC12T4V10

Features

- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

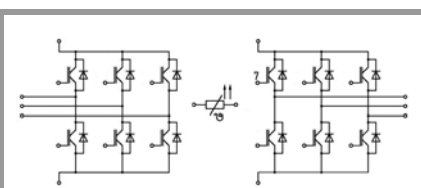
Typical Applications*

- 4Q inverters

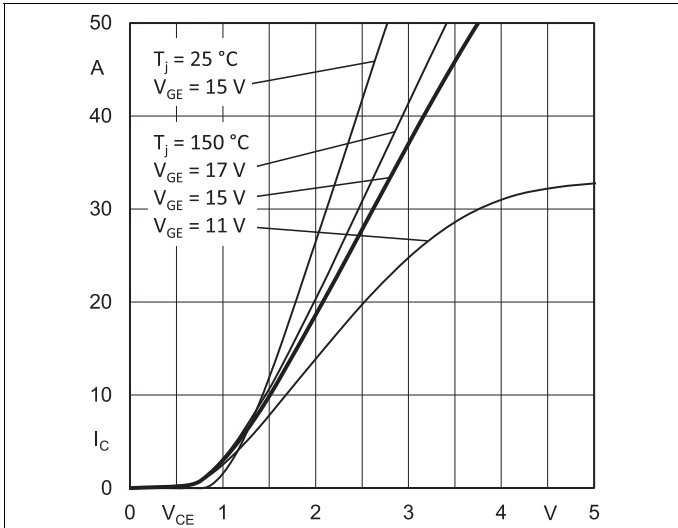
Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)
- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage $V_{DC} \leq 800\text{V}$
- Temperature sensor: no basic insulation to main circuit, signal processing with reference to -DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information

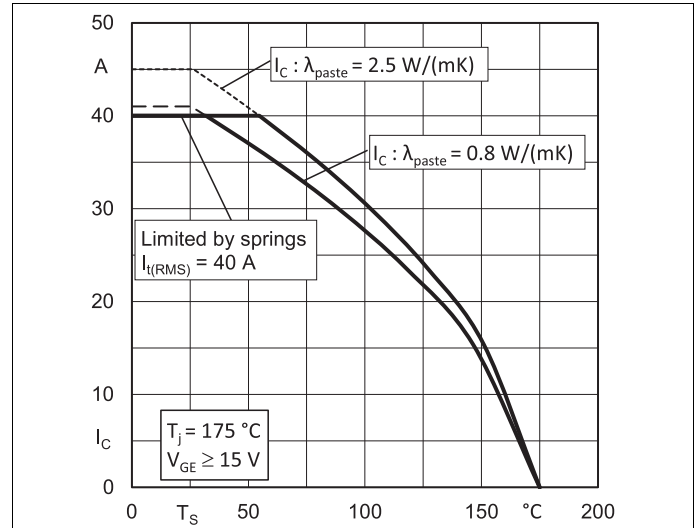
| Characteristics | | | | | | |
|---------------------------|---|---------------------------|------|------------------|------|---------------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| Diode 1 - 6 | | | | | | |
| $V_F = V_{EC}$ | $I_F = 25\text{ A}$ $V_{GE} = 0\text{ V}$ chiplevel | $T_j = 25^\circ\text{C}$ | | 2.41 | 2.74 | V |
| | | $T_j = 150^\circ\text{C}$ | | 2.45 | 2.79 | V |
| V_{F0} | chiplevel | $T_j = 25^\circ\text{C}$ | | 1.30 | 1.50 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.90 | 1.10 | V |
| r_F | chiplevel | $T_j = 25^\circ\text{C}$ | | 44 | 50 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 62 | 68 | m Ω |
| I_{RRM} | $I_F = 25\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 17 | | A |
| Q_{rr} | $di/dt_{off} = 380\text{ A}/\mu\text{s}$ $V_{GE} = -15\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 4 | | μC |
| E_{rr} | $V_{CC} = 600\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 1.4 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 1.52 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 1.31 | | K/W |
| Diode 7 - 12 | | | | | | |
| $V_F = V_{EC}$ | $I_F = 35\text{ A}$ $V_{GE} = 0\text{ V}$ chiplevel | $T_j = 25^\circ\text{C}$ | | 2.30 | 2.62 | V |
| | | $T_j = 150^\circ\text{C}$ | | 2.29 | 2.62 | V |
| V_{F0} | chiplevel | $T_j = 25^\circ\text{C}$ | | 1.30 | 1.50 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.90 | 1.10 | V |
| r_F | chiplevel | $T_j = 25^\circ\text{C}$ | | 29 | 32 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 40 | 43 | m Ω |
| I_{RRM} | $I_F = 35\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 28 | | A |
| Q_{rr} | $di/dt_{off} = 720\text{ A}/\mu\text{s}$ $V_{GE} = -15\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 5.8 | | μC |
| E_{rr} | $V_{CC} = 600\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 2.3 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 1.2 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 1 | | K/W |
| Module | | | | | | |
| L_{CE} | | | | 30 | | nH |
| M_s | to heat sink | | 2 | | 2.5 | Nm |
| w | | | | 55 | | g |
| Temperature Sensor | | | | | | |
| R_{100} | $T_r=100^\circ\text{C}$ ($R_{25}=1000\Omega$) | | | 1670 \pm 3% | | Ω |
| $R(T)$ | $R(T)=1000\Omega[1+A(T-25^\circ\text{C})+B(T-25^\circ\text{C})^2]$], $A = 7.635 \cdot 10^{-3} \text{ }^\circ\text{C}^{-1}$, $B = 1.731 \cdot 10^{-5} \text{ }^\circ\text{C}^{-2}$ | | | | | |



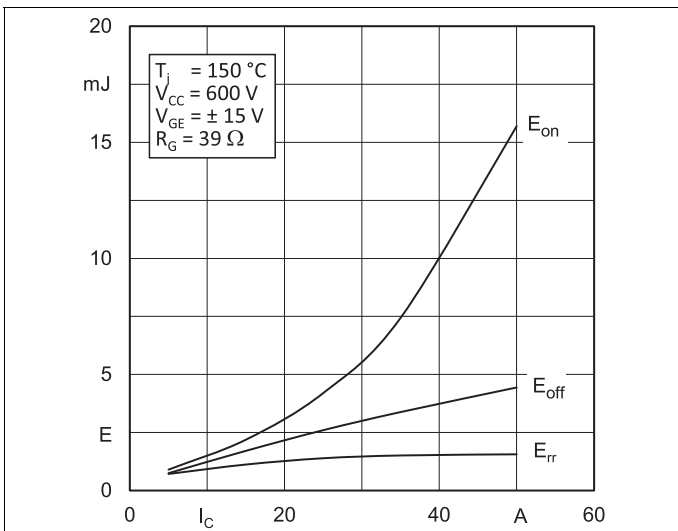
ACC



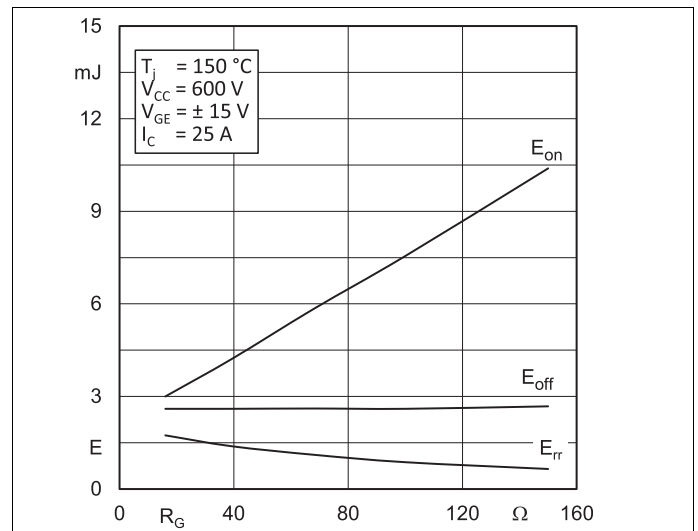
IGBT 1-6 - Fig. 1:
Typ. output characteristic



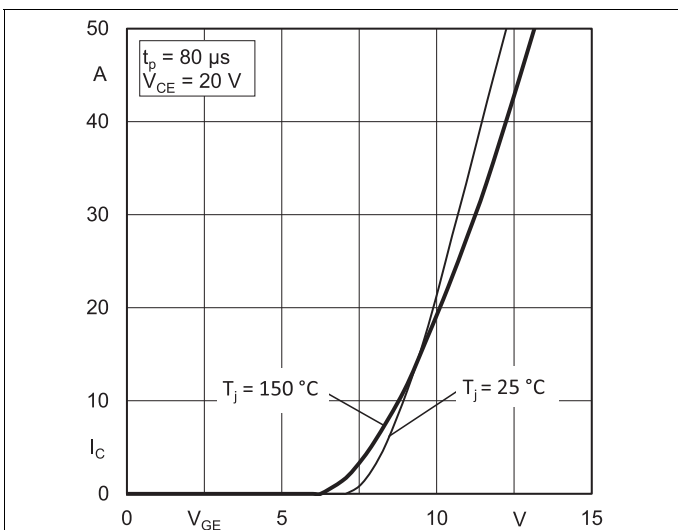
IGBT 1-6 - Fig. 2:
Typ. rated current vs. temperature $I_C = f(T_s)$



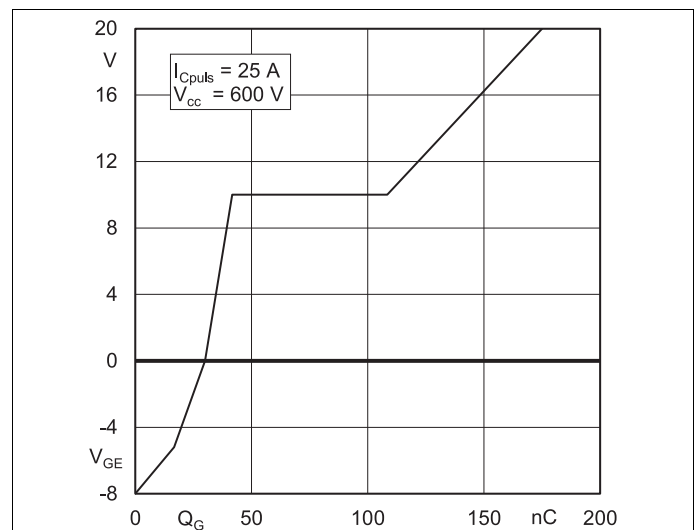
IGBT 1-6 - Fig. 3:
Typ. turn-on /-off energy = $f(I_C)$



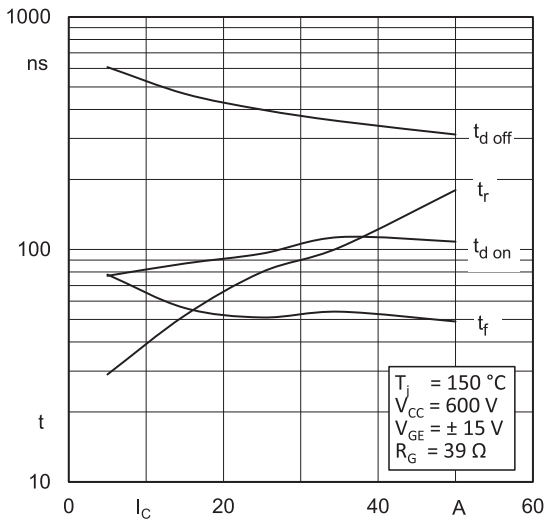
IGBT 1-6 - Fig. 4:
Typ. turn-on /-off energy = $f(R_G)$



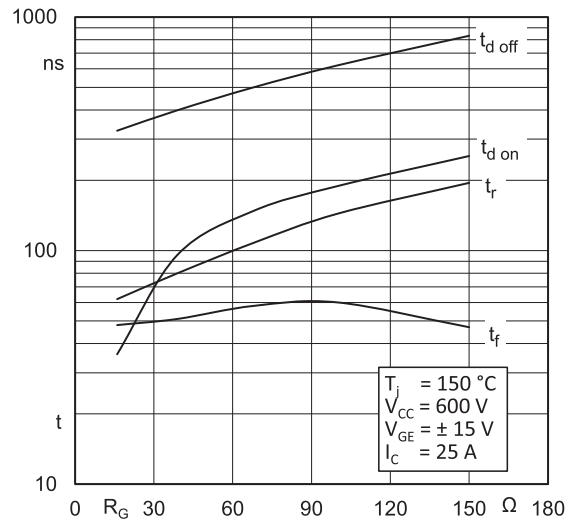
IGBT 1-6 - Fig. 5:
Typ. transfer characteristic



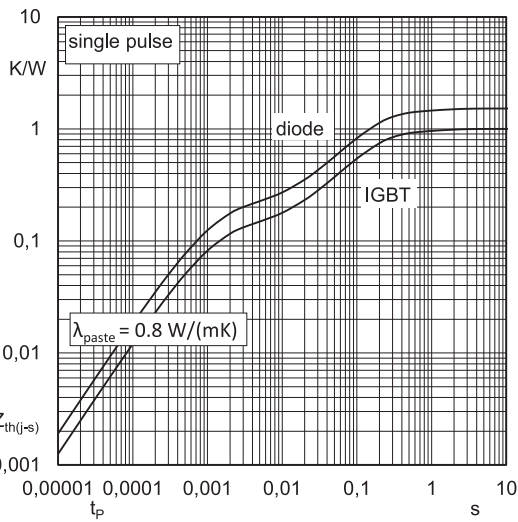
IGBT 1-6 - Fig. 6:
Typ. gate charge characteristic



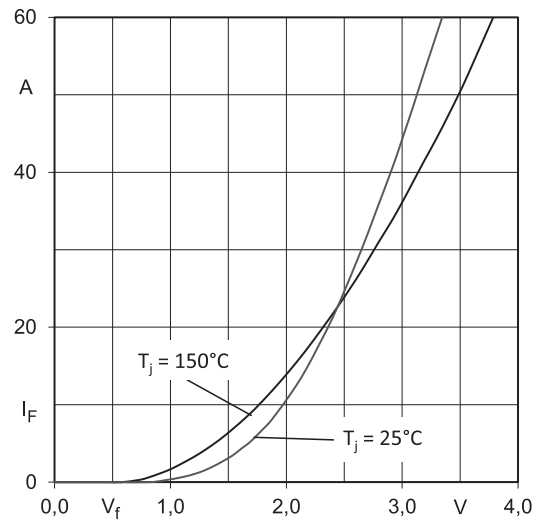
IGBT 1-6 - Fig. 7:
Typ. switching times vs. I_C



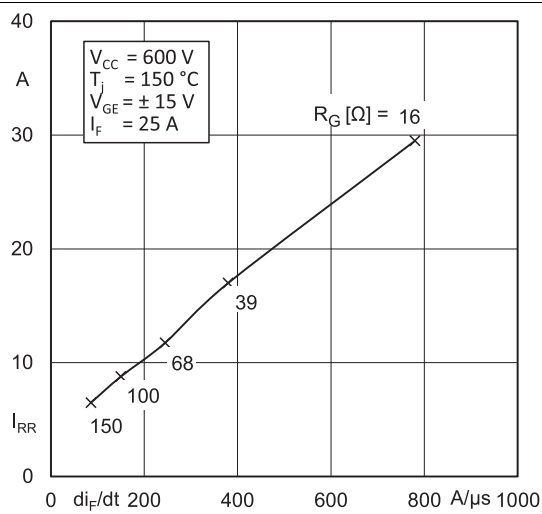
IGBT 1-6 - Fig. 8:
Typ. switching times vs. gate resistor R_G



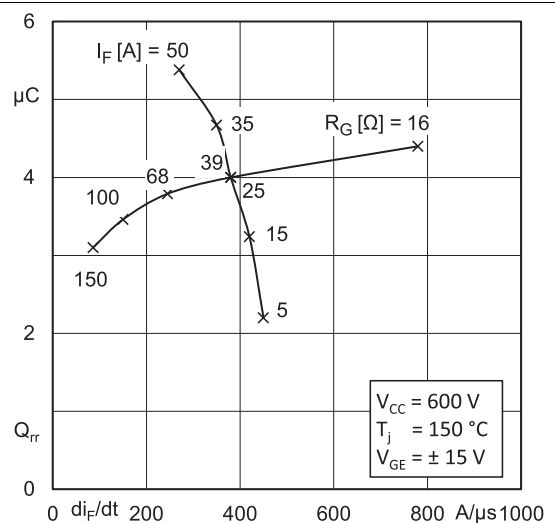
IGBT 1-6 - Fig. 9:
Transient thermal impedance of IGBT and Diode



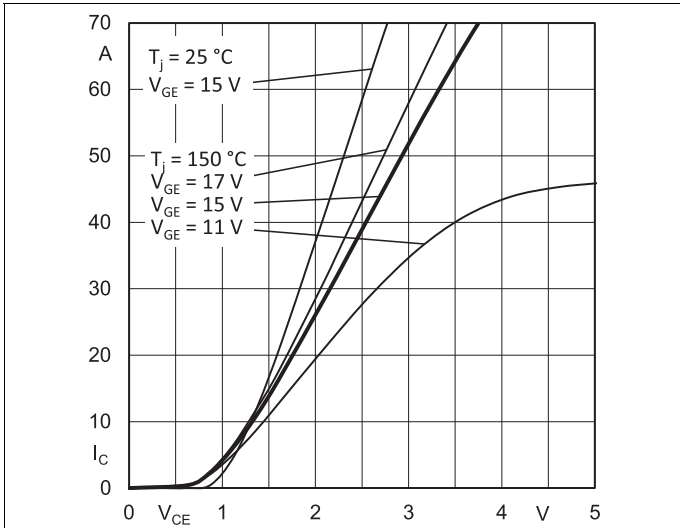
IGBT 1-6 - Fig. 10:
CAL diode forward characteristic



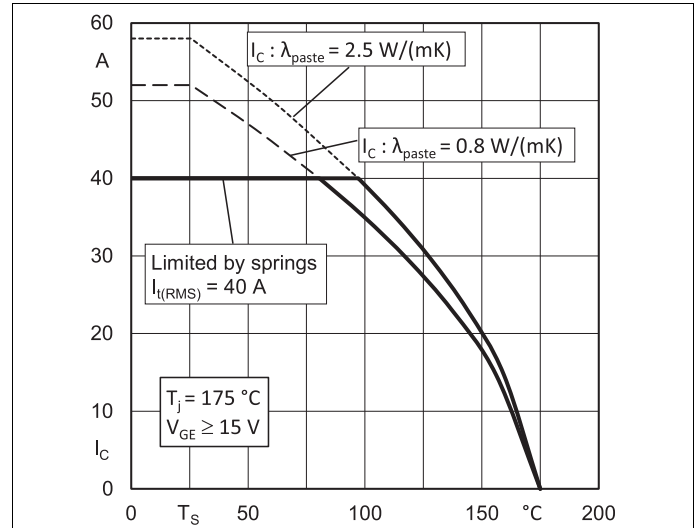
IGBT 1-6 - Fig. 11:
Typ. CAL diode peak reverse recovery current



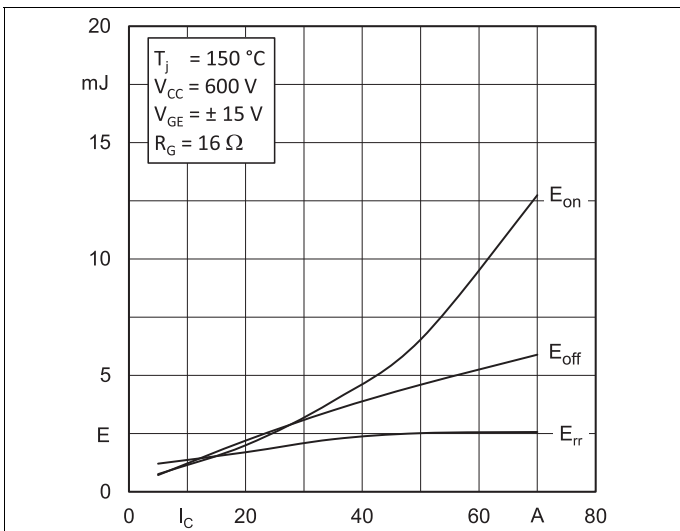
IGBT 1-6 - Fig. 12:
Typ. CAL diode recovery charge



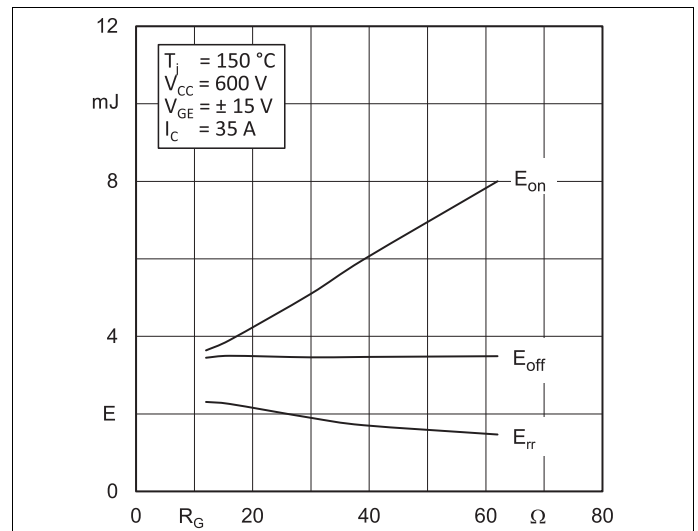
IGBT 7-12 - Fig. 1:
Typ. output characteristic



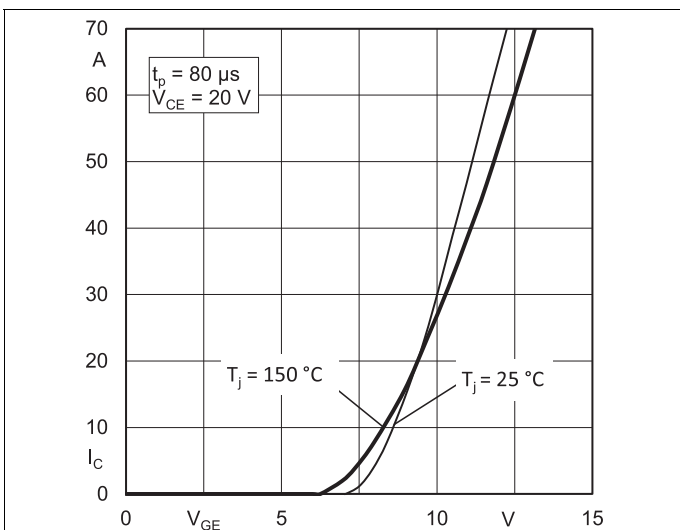
IGBT 7-12 - Fig. 2:
Typ. rated current vs. temperature $I_C = f(T_s)$



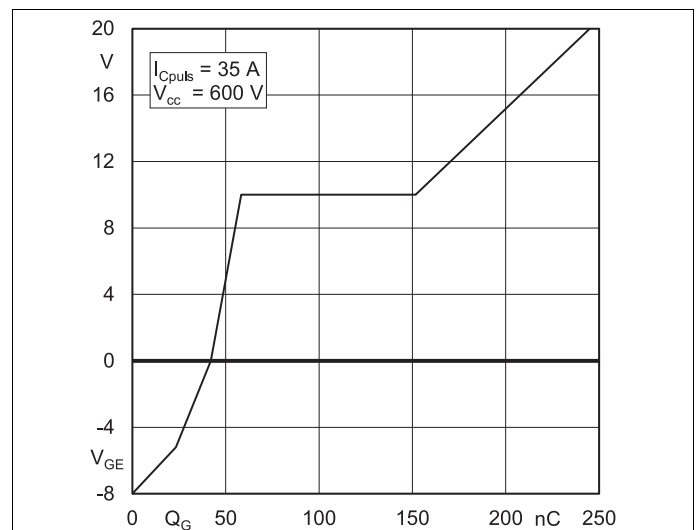
IGBT 7-12 - Fig. 3:
Typ. turn-on /-off energy = $f(I_C)$



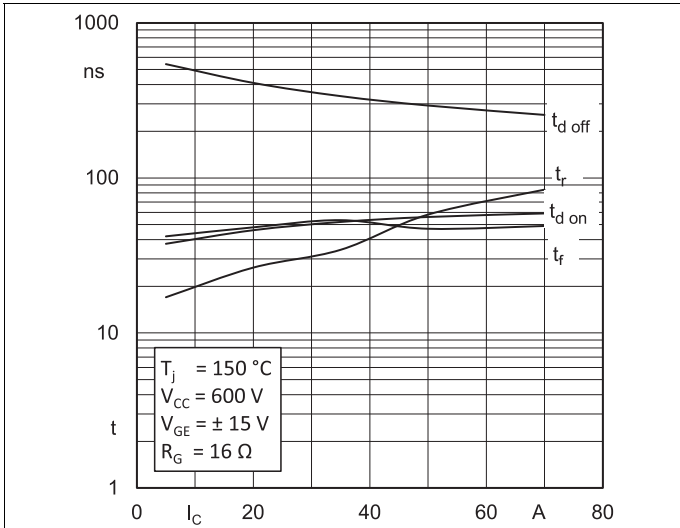
IGBT 7-12 - Fig. 4:
Typ. turn-on /-off energy = $f(R_G)$



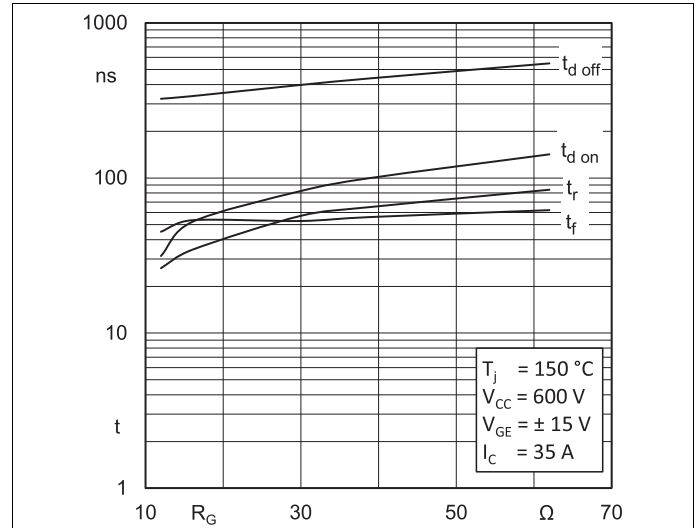
IGBT 7-12 - Fig. 5:
Typ. transfer characteristic



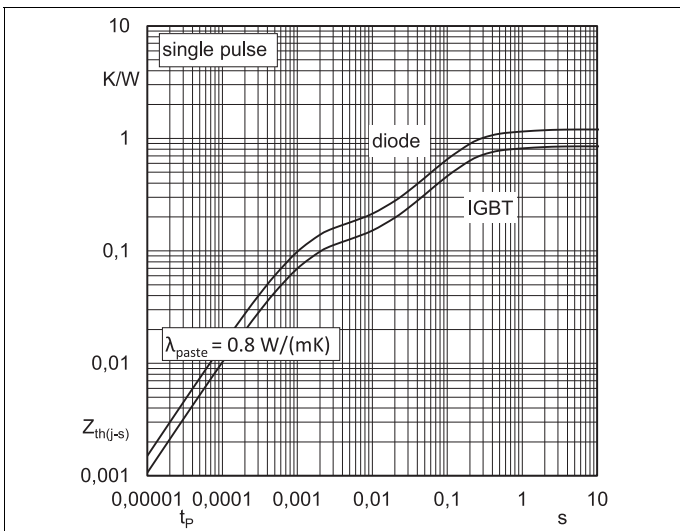
IGBT 7-12 - Fig. 6:
Typ. gate charge characteristic



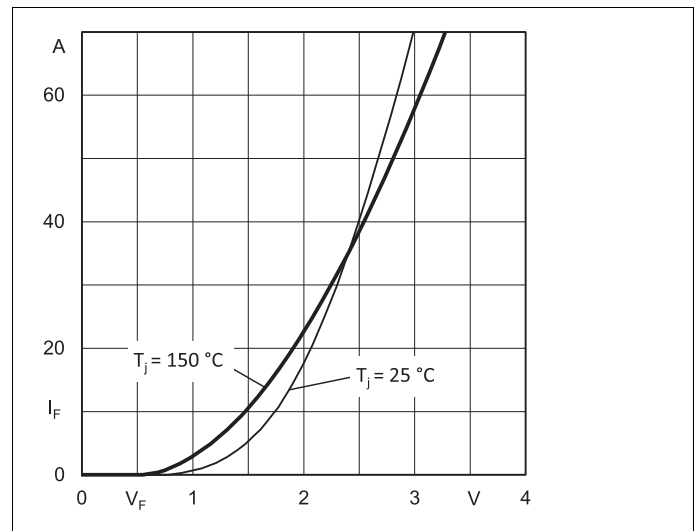
IGBT 7-12 - Fig. 7:
Typ. switching times vs. I_C



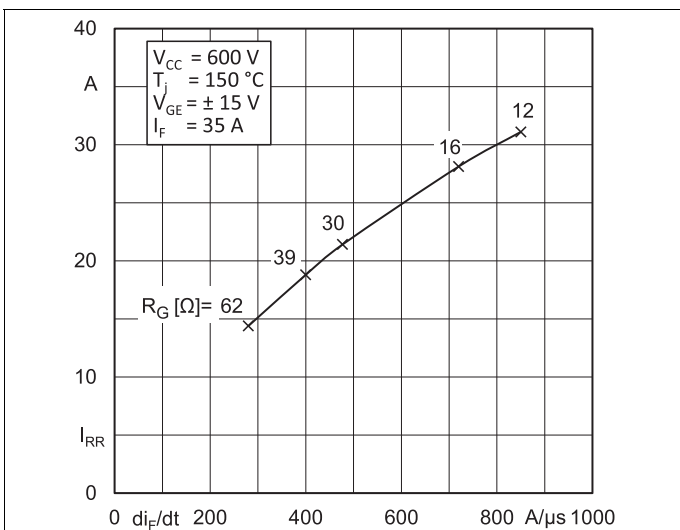
IGBT 7-12 - Fig. 8:
Typ. switching times vs. gate resistor R_G



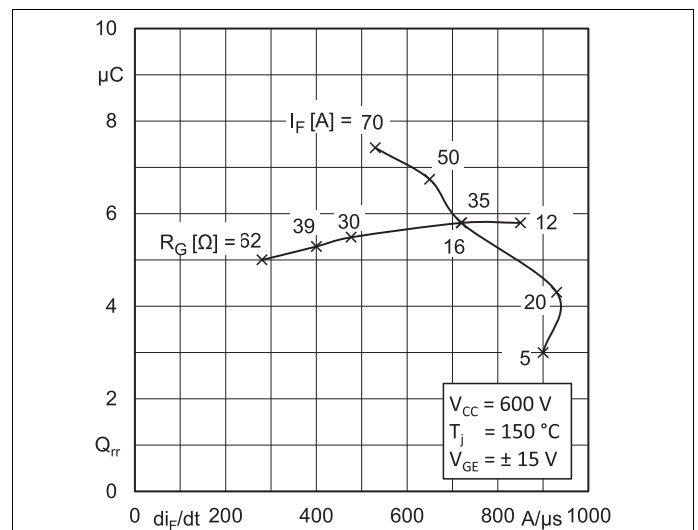
IGBT 7-12 - Fig. 9:
Transient thermal impedance of IGBT and Diode



IGBT 7-12 - Fig. 10:
CAL diode forward characteristic



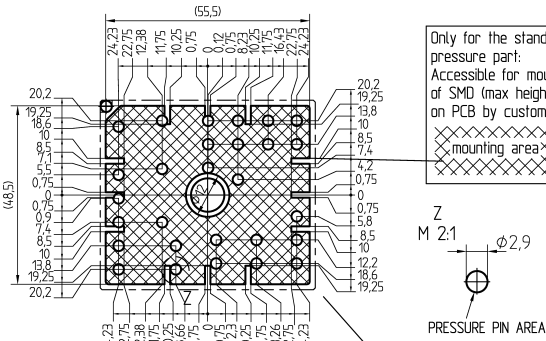
IGBT 7-12 - Fig. 11:
Typ. CAL diode peak reverse recovery current



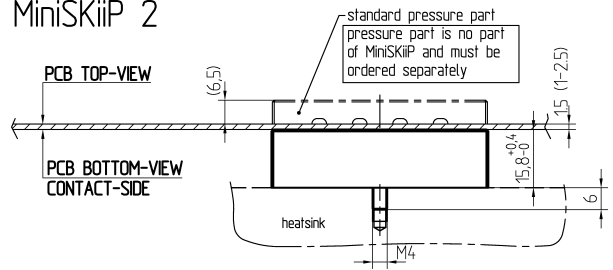
IGBT 7-12 - Fig. 12:
Typ. CAL diode recovery charge

SKiiP 24ACC12T4V10

PCB PCB TOP-VIEW



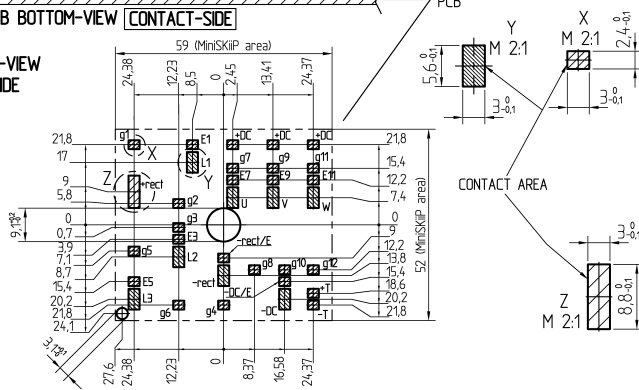
MiniSKiiP 2



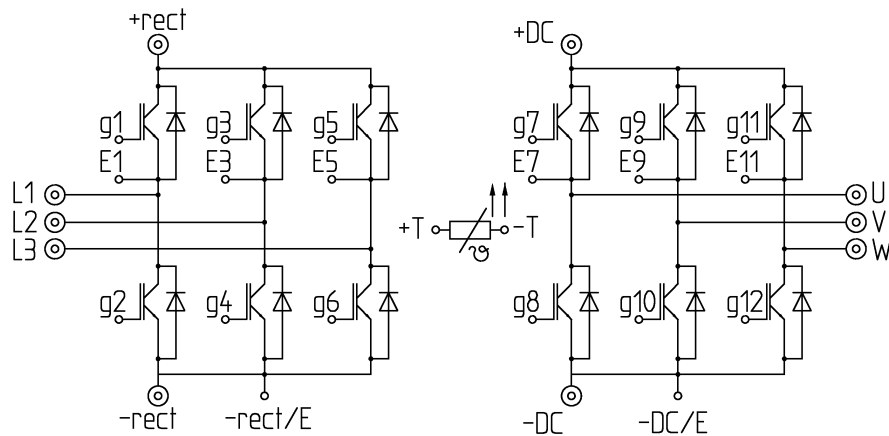
PCB TOP-VIEW

PCB BOTTOM-VIEW CONTACT-SIDE

PCB BOTTOM-VIEW CONTACT-SIDE



pinout, dimensions



- ⊙ power connector
- control connector

pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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